

Amendments to the Claims:

This listing of claims replaces all prior versions and listings of claims in the application:

Listing of Claims:

Claim 1 (canceled)

Claim 2. (New) A portable phone comprising:

a body;

a semiconductor device contained in the body, said semiconductor device comprising:

a substrate;

a passive component including at least an inductor formed over the substrate;

an insulating film covering said passive component;

an insulation layer attached to said insulating film via an adhesive;

a circuit including at least one thin film transistor formed over said insulation layer,

wherein said circuit is electrically connected to said passive component by at least one electrode through an opening of said insulation layer .

Claim 3. (New) The portable phone according to claim 2 wherein said substrate is a quartz substrate.

Claim 4. (New) The portable phone according to claim 2 wherein said insulation layer comprises aluminum nitride.

Claim 5. (New) A portable phone comprising:

a substrate;
a passive component including at least a capacitor formed over the substrate;
an insulating film covering said passive component;
an insulation layer attached to said insulating film via an adhesive;
a circuit including at least one thin film transistor formed over said insulation layer,
wherein said circuit is electrically connected to said passive component by at least one electrode through an opening of said insulation layer.

Claim 6. (New) The portable phone according to claim 5 wherein said substrate is a quartz substrate .

Claim 7. (New) The portable phone according to claim 5 wherein said insulation layer comprises aluminum nitride.

Claim 8. (New) A portable phone comprising:

a body; and
a semiconductor device contained in the body, said semiconductor device comprising:
a substrate;
a passive component including at least a SAW filter formed over the substrate;
an insulating film covering said passive component;
an insulation layer attached to said insulating film via an adhesive;
a circuit including at least one thin film transistor formed over said insulation layer,
wherein said circuit is electrically connected to said passive component by at least one electrode through an opening of said insulation layer.

Claim 9. (New) The portable phone according to claim 8 wherein said substrate is a quartz substrate.

Claim 10. (New) The portable phone according to claim 8 wherein said layer comprises aluminum nitride.

Claim 11. (New) A portable phone comprising:

- a body; and

- a semiconductor device contained in the body, said semiconductor device comprising:

- a substrate;

- a passive component including at least a band-pass filter formed over the substrate;

- an insulating film covering said passive component;

- an insulation layer attached to said insulating film via an adhesive;

- a circuit including at least one thin film transistor formed over said insulation layer,

- wherein said circuit is electrically connected to said passive component by at least one electrode through an opening of said insulation layer.

Claim 12. (New) The portable phone according to claim 11 wherein said substrate is a quartz substrate.

Claim 13. (New) The portable phone according to claim 11 wherein said layer comprises aluminum nitride.

Claim 14. (New) A portable phone comprising:

- a body; and

- a semiconductor device contained in the body, said semiconductor device comprising:

a substrate;
an oscillating component formed over the substrate;
an insulating film covering said oscillating component;
an insulation layer attached to said insulating film via an adhesive;
a circuit including at least one thin film transistor formed over said insulation layer,
wherein said circuit is electrically connected to said passive component by at least one electrode through an opening of said insulation layer.

Claim 15. (New) The portable phone according to claim 14 wherein said substrate is a quartz substrate.

Claim 16. (New) The portable phone according to claim 14 wherein said layer comprises aluminum nitride.

Claim 17. (New) The portable phone according to claim 2 wherein said semiconductor device is a mobile phone.

Claim 18. (New) A portable phone comprising:

a body; and
a semiconductor device contained in the body, said semiconductor device comprising:
a substrate;
a passive component including at least a band pass filter formed over the substrate;
an insulating film covering said passive component;
an insulation layer attached to said insulating film via an adhesive;
a circuit including at least one thin film transistor formed over said insulation layer;

wherein said circuit is electrically connected to said passive component by at least one electrode through an opening of said insulation layer.

Claim 19. (New) The portable phone according to claim 18 wherein said substrate is a quartz substrate.

Claim 20. (New) The portable phone according to claim 17 wherein said layer comprises aluminum nitride.